

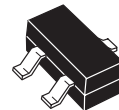
The RF Line
NPN Silicon
Low Noise, High-Frequency
Transistors

Designed for use in high gain, low noise small-signal amplifiers. This series features excellent broadband linearity and is offered in a variety of packages.

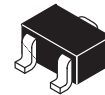
- Fully Implanted Base and Emitter Structure
- 9 Finger, 1.25 Micron Geometry with Gold Top Metal
- Gold Sintered Back Metal
- Available in tape and reel packaging options:
 - T1 suffix = 3,000 units per reel
 - T3 suffix = 10,000 units per reel

MMBR941
MRF947
SERIES

$I_C = 50 \text{ mA}$
LOW NOISE
HIGH-FREQUENCY
TRANSISTORS



CASE 318-08, STYLE 6
SOT-23
LOW PROFILE
MMBR941LT1, T3, MMBR941BLT1



CASE 419-02, STYLE 3
MRF947AT1, MRF947BT1,
MRF947T1, T3

LIFETIME BUY

LAST SHIP: 26MAR02
LAST ORDER: 25SEP01



MAXIMUM RATINGS

Rating	Symbol	MMBR941LT1, T3	MRF947 Series	Unit
Collector–Emitter Voltage	V_{CE0}	10	10	Vdc
Collector–Base Voltage	V_{CB0}	20	20	Vdc
Emitter–Base Voltage	V_{EBO}	1.5	1.5	Vdc
Power Dissipation (1) $T_C = 75^\circ\text{C}$ Derate linearly above $T_{\text{case}} = 75^\circ\text{C}$ @	$P_{D\text{max}}$	0.25 3.33	0.188 2.5	Watts mW/ $^\circ\text{C}$
Collector Current — Continuous (2)	I_C	50	50	mA
Maximum Junction Temperature	$T_{J\text{max}}$	150	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	–55 to +150	–55 to +150	$^\circ\text{C}$
Thermal Resistance, Junction to Case	$R_{\theta\text{JC}}$	300	400	$^\circ\text{C}/\text{W}$

DEVICE MARKING

MMBR941LT1 = 7Y MRF947AT1 = G	MMBR941BLT1 = 7N	MRF947T1, T3 = A	MRF947BT1 = H
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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS (3)

Collector–Emitter Breakdown Voltage ($I_C = 0.1\text{ mA}$, $I_B = 0$)	All	$V_{(\text{BR})\text{CEO}}$	10	12	—	Vdc
Collector–Base Breakdown Voltage ($I_C = 0.1\text{ mA}$, $I_E = 0$)	All	$V_{(\text{BR})\text{CBO}}$	20	23	—	Vdc
Emitter Cutoff Current ($V_{EB} = 1.0\text{ V}$, $I_C = 0$)	All	I_{EBO}	—	—	0.1	μAdc
Collector Cutoff Current ($V_{CB} = 10\text{ V}$, $I_E = 0$)	All	I_{CBO}	—	—	0.1	μAdc

ON CHARACTERISTICS (3)

DC Current Gain ($V_{CE} = 6.0\text{ V}$, $I_C = 5.0\text{ mA}$) (MMBR941LT1) (MMBR941BLT1)		h_{FE}	50 100	— —	200 200	—
DC Current Gain ($V_{CE} = 1.0\text{ V}$, $I_C = 500\text{ }\mu\text{A}$)	MRF947T1, MRF947BT1	h_{FE1}	50	—	—	—
DC Current Gain ($V_{CE} = 6.0\text{ V}$, $I_C = 5.0\text{ mA}$)	MRF947T1, T3 MRF947AT1 MRF947BT1	h_{FE2} h_{FE3} h_{FE4}	50 75 100	— — —	— 150 200	—

DYNAMIC CHARACTERISTICS

Collector–Base Capacitance ($V_{CB} = 10\text{ V}$, $I_E = 0$, $f = 1.0\text{ MHz}$)	All	C_{cb}	—	0.35	—	pF
Current Gain — Bandwidth Product ($V_{CE} = 6.0\text{ V}$, $I_C = 15\text{ mA}$, $f = 1.0\text{ GHz}$)	All	f_T	—	8.0	—	GHz

NOTE:

- To calculate the junction temperature use $T_J = P_D \times R_{\theta\text{JC}} + T_{\text{CASE}}$. Case temperature measured on collector lead immediately adjacent to body of package.
- I_C — Continuous (MTBF ≈ 10 years).
- Pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$ pulsed.

PERFORMANCE CHARACTERISTICS

Conditions	Symbol	MMBR941LT1, T3			MRF947 Series			Unit
		Min	Typ	Max	Min	Typ	Max	
Insertion Gain ($V_{CE} = 6.0\text{ V}$, $I_C = 15\text{ mA}$, $f = 1.0\text{ GHz}$) ($V_{CE} = 6.0\text{ V}$, $I_C = 15\text{ mA}$, $f = 2.0\text{ GHz}$)	$ S_{21} ^2$	—	14 8.0	—	—	14 10.8	—	dB
Maximum Unilateral Gain (1) ($V_{CE} = 6.0\text{ V}$, $I_C = 15\text{ mA}$, $f = 1.0\text{ GHz}$) ($V_{CE} = 6.0\text{ V}$, $I_C = 15\text{ mA}$, $f = 2.0\text{ GHz}$)	$G_{U\text{ max}}$	—	16 10	—	—	14.8 11.6	—	dB
Noise Figure — Minimum (Figure 9) ($V_{CE} = 6.0\text{ V}$, $I_C = 5.0\text{ mA}$, $f = 1.0\text{ GHz}$) ($V_{CE} = 6.0\text{ V}$, $I_C = 5.0\text{ mA}$, $f = 2.0\text{ GHz}$)	NF_{MIN}	—	1.5 2.1	—	—	1.5 2.1	—	dB
Associated Gain at Minimum NF (Figure 9) ($V_{CE} = 6.0\text{ V}$, $I_C = 5.0\text{ mA}$, $f = 1.0\text{ GHz}$) ($V_{CE} = 6.0\text{ V}$, $I_C = 5.0\text{ mA}$, $f = 2.0\text{ GHz}$)	G_{NF}	—	14 8.5	—	—	14 10	—	dB
Noise Figure — 50 ohm Source ($V_{CE} = 6.0\text{ V}$, $I_C = 5.0\text{ mA}$, $f = 1.0\text{ GHz}$)	$NF_{50\ \Omega}$	—	1.9	2.8	—	1.9	2.8	dB

NOTE:

1. Maximum Unilateral Gain is $G_{U\text{ max}} = \frac{|S_{21}|^2}{(1-|S_{11}|^2)(1-|S_{22}|^2)}$

**TYPICAL CHARACTERISTICS
MMBR941LT1, T3; MMBR941BLT1**

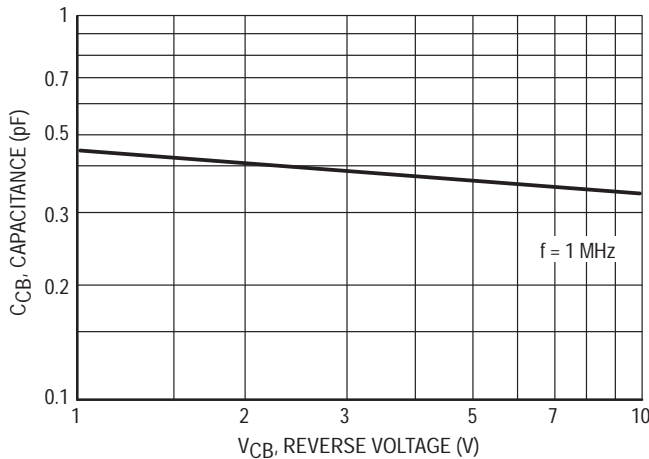


Figure 1. Collector-Base Capacitance versus Voltage

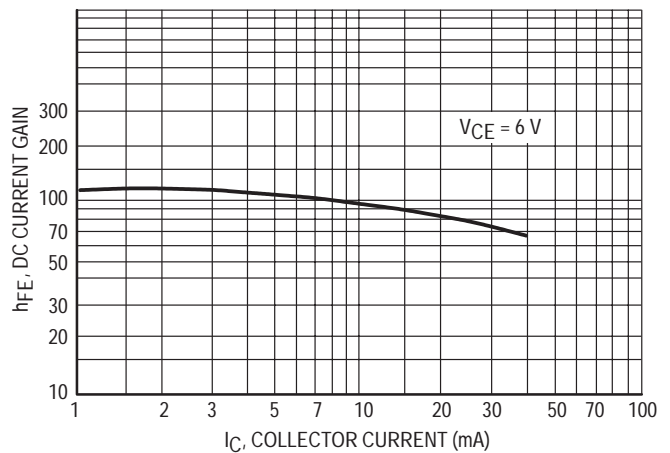


Figure 2. DC Current Gain versus Collector Current

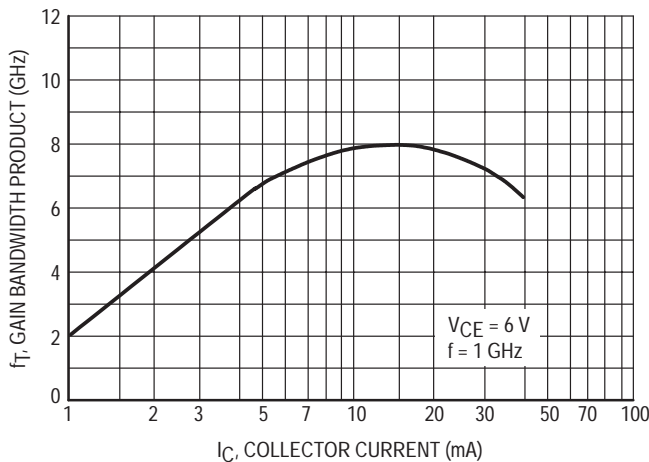


Figure 3. Gain Bandwidth Product versus Collector Current

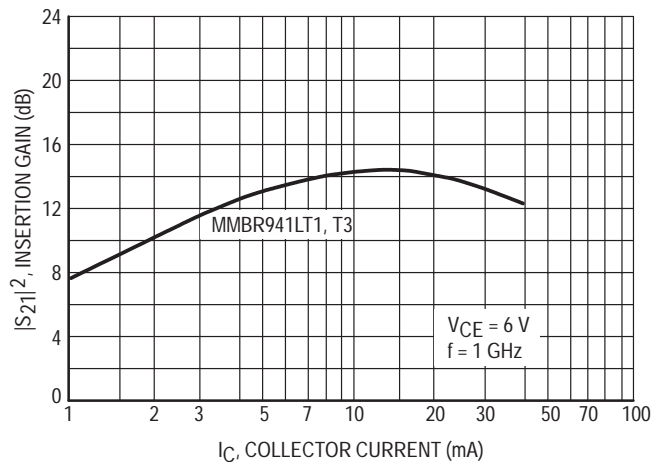


Figure 4. Insertion Gain versus Collector Current

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LAST SHIP: 26MAR02
LAST ORDER: 25SEP01

**FORWARD INSERTION GAIN AND
MAXIMUM UNILATERAL GAIN versus FREQUENCY**

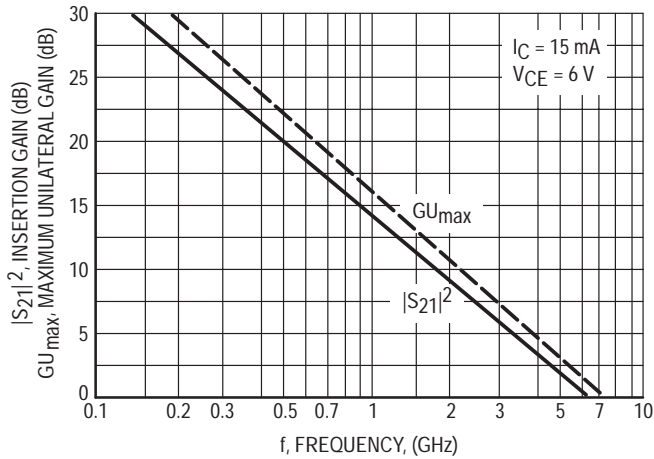


Figure 5. MMBR941LT1, T3

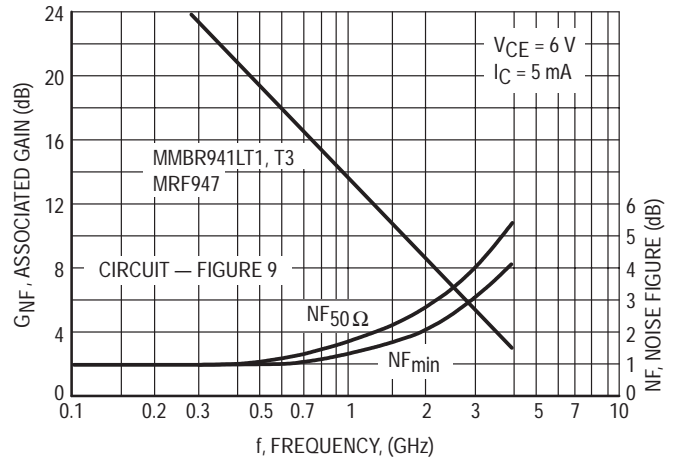


Figure 6. Noise Figure and Associated Gain versus Frequency

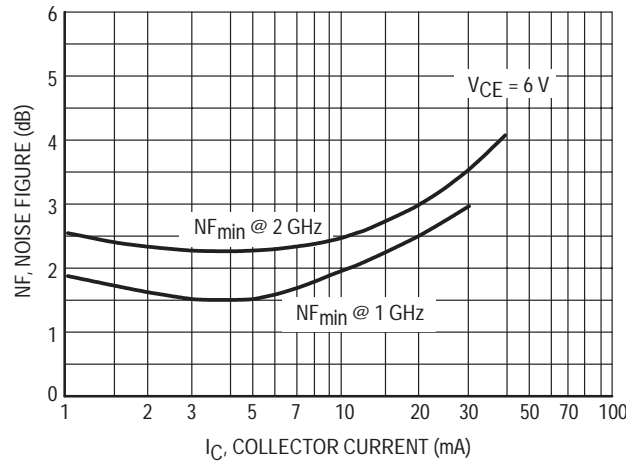


Figure 7. Minimum Noise Figure versus Collector Current

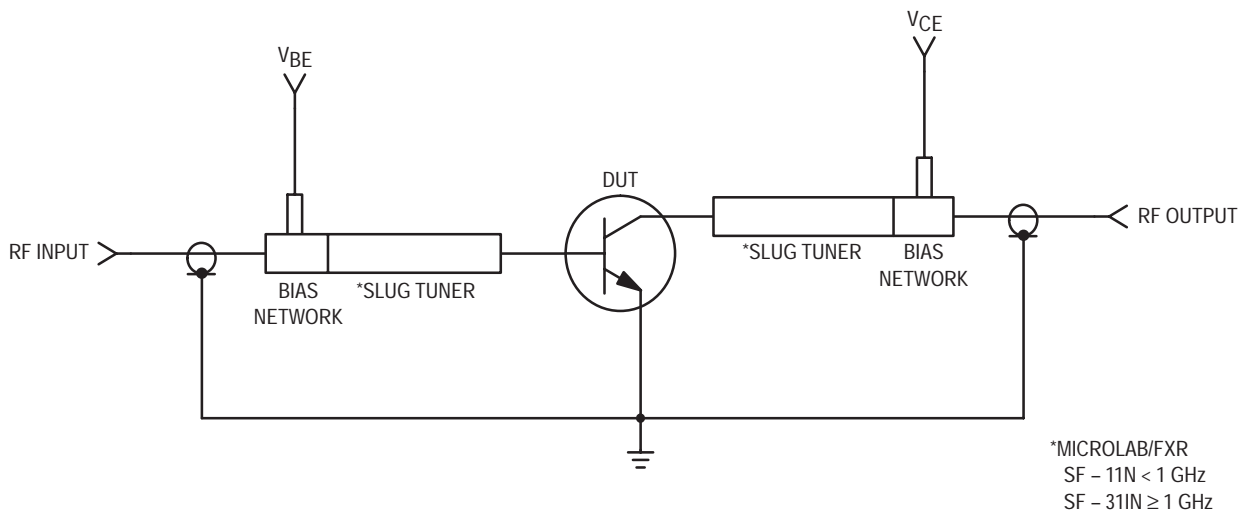


Figure 8. Functional Circuit Schematic (all devices)

TYPICAL CHARACTERISTICS
MRF947 SERIES

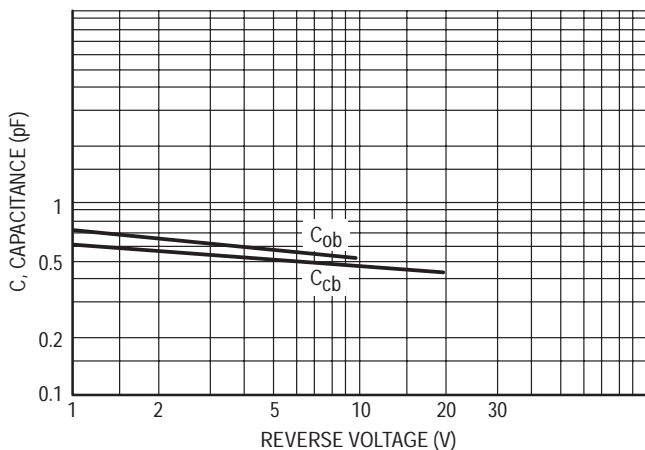


Figure 9. Capacitance versus Voltage

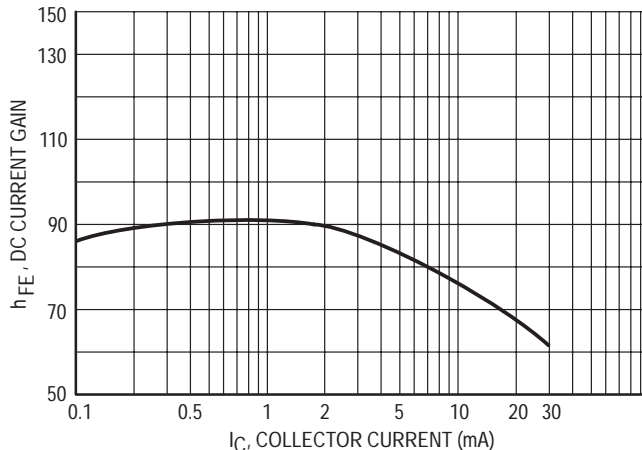


Figure 10. DC Current Gain versus Collector Current

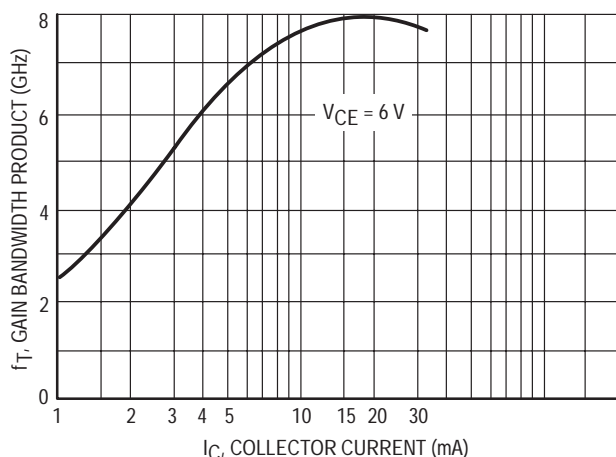


Figure 11. Gain-Bandwidth Product versus Collector Current

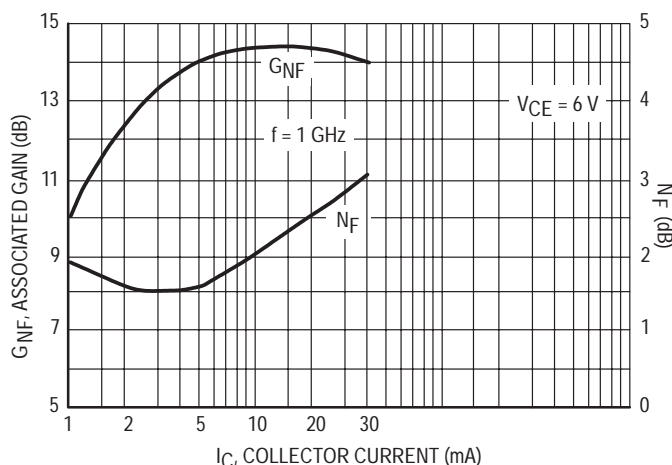


Figure 12. Associated Gain and Minimum Noise Figure versus Collector Current

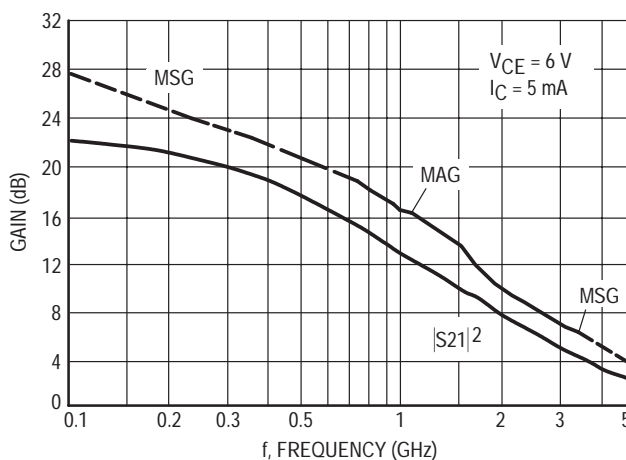


Figure 13. Forward Insertion Gain and Maximum Stable/Available Power Gain versus Frequency

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LAST ORDER: 25SEP01

V _{CE} (Volts)	I _C (mA)	f (MHz)	S ₁₁		S ₂₁		S ₁₂		S ₂₂		
			Mag	∠φ	Mag	∠φ	Mag	∠φ	Mag	∠φ	
1.0	0.5	100	0.97	-11	1.78	170	0.03	83	0.99	-4.7	
		200	0.96	-22	1.74	161	0.06	76	0.99	-9.1	
		500	0.90	-53	1.60	133	0.13	56	0.93	-21	
		900	0.75	-89	1.37	105	0.18	37	0.83	-33	
		1000	0.72	-98	1.32	100	0.18	33	0.82	-36	
		1500	0.63	-132	1.07	74	0.19	20	0.75	-47	
		2000	0.57	-163	0.89	55	0.16	15	0.72	-57	
		3000	0.55	144	0.67	30	0.15	40	0.71	-76	
		1.0	100	0.95	-13	3.37	169	0.03	81	0.99	-6.2
	200		0.93	-27	3.27	158	0.06	73	0.98	-12	
	500		0.81	-62	2.85	128	0.12	52	0.86	-26	
	900		0.63	-101	2.21	101	0.15	37	0.73	-38	
	1000		0.60	-110	2.08	96	0.15	34	0.71	-40	
	1500		0.51	-144	1.59	73	0.16	27	0.64	-49	
	2000		0.46	-173	1.28	56	0.16	29	0.61	-58	
	3000		0.46	138	0.95	30	0.19	44	0.60	-75	
	6.0		5.0	100	0.82	-25	14.6	159	0.02	77	0.94
		200		0.75	-47	12.6	142	0.04	68	0.85	-22
400		0.55		-79	9.2	120	0.05	61	0.69	-31	
600		0.42		-98	6.9	106	0.07	60	0.60	-32	
800		0.33		-114	5.3	97	0.08	61	0.56	-33	
1000		0.28		-129	4.5	90	0.09	62	0.52	-33	
1500		0.25		-155	3.1	77	0.13	67	0.51	-37	
2000		0.16		176	2.4	66	0.16	68	0.51	-36	
2500		0.21		151	2.0	57	0.20	69	0.48	-40	
3000		0.18		122	1.7	50	0.23	68	0.48	-44	
3500		0.30		108	1.5	42	0.27	66	0.45	-46	
4000		0.29		91	1.4	37	0.32	64	0.42	-53	
10		100		0.67	-37	23.5	149	0.02	74	0.88	-18
		200		0.54	-64	18.1	129	0.03	68	0.73	-28
		400		0.37	-96	11.3	108	0.05	67	0.56	-31
		600		0.26	-114	8.0	98	0.06	67	0.50	-30
		800	0.21	-130	6.0	91	0.08	70	0.47	-30	
		1000	0.18	-147	5.1	85	0.09	70	0.45	-30	
		1500	0.18	-167	3.4	74	0.13	72	0.46	-34	
		2000	0.11	159	2.6	64	0.17	71	0.46	-34	
		2500	0.17	140	2.2	56	0.21	69	0.44	-38	
		3000	0.15	107	1.8	59	0.25	67	0.45	-41	
		3500	0.27	100	1.7	42	0.28	65	0.42	-42	
		4000	0.26	85	1.5	37	0.33	61	0.39	-49	
15		100	0.56	-46	28.6	143	0.02	73	0.83	-22	
		200	0.43	-75	20.2	122	0.03	67	0.65	-30	
		400	0.29	-107	11.8	104	0.04	70	0.50	-30	
		600	0.22	-125	8.2	95	0.06	74	0.46	-28	
		800	0.18	-141	6.2	88	0.08	74	0.45	-27	
		1000	0.16	-158	5.1	83	0.09	74	0.43	-28	
		1500	0.17	-174	3.4	72	0.13	73	0.44	-32	
		2000	0.11	150	2.6	63	0.17	72	0.45	-33	
		2500	0.17	138	2.2	55	0.21	70	0.43	-37	
		3000	0.15	102	1.9	49	0.25	67	0.44	-39	
		3500	0.28	98	1.7	42	0.29	65	0.40	-41	
		4000	0.25	82	1.5	37	0.32	61	0.38	-47	

Table 1. MMBR941LT1, T3 Common Emitter S-Parameters

VCE (Volts)	I _C (mA)	f (MHz)	S ₁₁		S ₂₁		S ₁₂		S ₂₂	
			Mag	∠φ	Mag	∠φ	Mag	∠φ	Mag	∠φ
6.0	20	100	0.49	-52	31.5	139	0.01	70	0.79	-23
		200	0.36	-84	21.1	118	0.02	69	0.60	-29
		400	0.25	-115	12.1	101	0.04	73	0.48	-29
		600	0.20	-134	8.3	93	0.06	74	0.45	-26
		800	0.16	-150	6.2	87	0.07	75	0.44	-26
		1000	0.15	-166	5.1	82	0.09	75	0.42	-26
		1500	0.16	-176	3.5	75	0.14	74	0.44	-31
		2000	0.12	144	2.6	63	0.17	73	0.45	-32
		2500	0.17	133	2.2	55	0.22	70	0.43	-36
		3000	0.16	101	1.9	49	0.25	68	0.44	-39
	3500	0.28	98	1.6	41	0.29	65	0.41	-40	
	4000	0.26	82	1.5	36	0.33	61	0.39	-47	
	30	100	0.41	-65	34.3	134	0.01	70	0.74	-25
		200	0.30	-99	21.6	113	0.02	70	0.56	-28
		400	0.23	-131	11.9	98	0.04	76	0.47	-25
		600	0.20	-147	8.1	91	0.06	76	0.45	-24
		800	0.18	-163	6.1	84	0.07	78	0.44	-23
		1000	0.17	-177	5.0	80	0.09	78	0.43	-24
		1500	0.18	174	3.4	70	0.13	76	0.45	-30
		2000	0.14	141	2.5	61	0.17	74	0.47	-31
2500		0.20	131	2.1	54	0.21	71	0.45	-36	
3000		0.18	104	1.8	47	0.25	69	0.46	-39	
3500	0.31	100	1.6	40	0.29	65	0.42	-42		
4000	0.29	84	1.5	35	0.33	62	0.40	-48		

Table 1. MMBR941LT1, T3 Common Emitter S-Parameters (continued)

VCE (Vdc)	IC (mA)	f (MHz)	NF _{min} (dB)	Γ _o (MAG, ANGLE)	r _N
6	5	1000	1.5	0.33 ∠ 77	0.28
		1500	1.75	0.26 ∠ 141	0.3

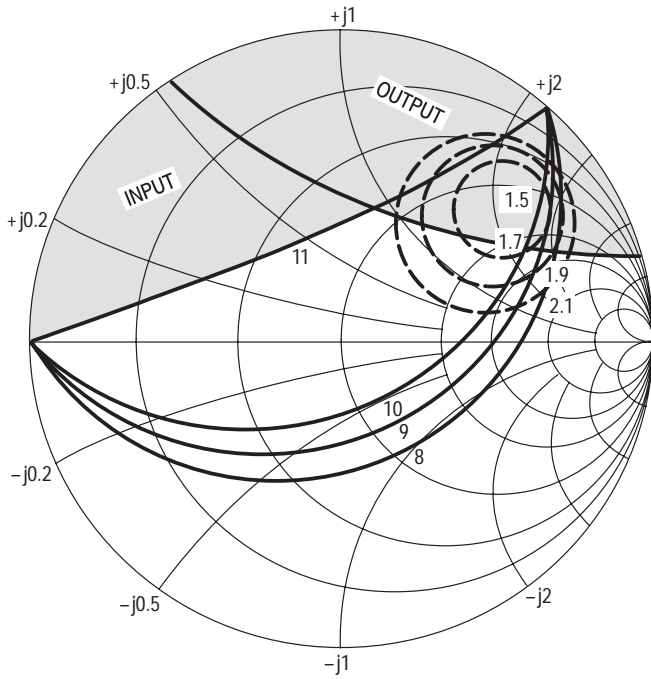
Table 2. MRF947 Series Typical Noise Parameters

VCE (Volts)	IC (mA)	f (MHz)	S ₁₁		S ₂₁		S ₁₂		S ₂₂	
			Mag	∠φ	Mag	∠φ	Mag	∠φ	Mag	∠φ
1.0	0.5	100	0.966	-11	1.776	170	0.031	83	0.998	-5
		200	0.956	-23	1.735	161	0.061	75	0.991	-9
		500	0.892	-55	1.587	132	0.135	55	0.923	-21
		900	0.749	-91	1.355	104	0.185	35	0.827	-34
		1000	0.720	-100	1.300	98	0.190	32	0.808	-36
		1500	0.637	-134	1.057	73	0.196	18	0.743	-47
		2000	0.587	-164	0.883	53	0.176	12	0.708	-58
		3000	0.572	149	0.672	27	0.149	33	0.680	-82
	1.0	100	0.941	-14	3.391	168	0.031	81	0.991	-6
		200	0.921	-28	3.285	158	0.060	73	0.974	-12
		500	0.806	-65	2.844	128	0.123	51	0.852	-27
		900	0.638	-104	2.196	101	0.158	35	0.717	-39
		1500	0.533	-146	1.580	72	0.168	25	0.619	-50
		2000	0.495	-174	1.281	55	0.164	25	0.581	-60
2.0	0.5	100	0.979	-9	1.827	173	0.030	85	0.996	-4
		200	0.960	-18	1.909	165	0.060	80	0.991	-9
		500	0.920	-43	1.652	144	0.132	65	0.940	-19
		1000	0.749	-77	1.451	116	0.196	47	0.842	-32
		1500	0.674	-105	1.190	94	0.214	36	0.774	-39
		2000	0.548	-128	1.077	79	0.189	33	0.692	-43
		3000	0.480	-178	0.808	60	0.153	55	0.625	-52
		2.0	100	0.907	-16	6.640	167	0.029	81	0.977
	200		0.846	-32	6.419	156	0.054	73	0.944	-17
	500		0.711	-68	4.874	128	0.104	57	0.770	-32
	1000		0.495	-106	3.178	103	0.138	50	0.603	-41
	1500		0.405	-131	2.358	86	0.157	52	0.542	-45
	2000		0.314	-155	1.910	75	0.173	58	0.490	-44
	5.0	100	0.780	-28	14.100	159	0.027	78	0.932	-15
200		0.676	-51	12.219	142	0.046	67	0.831	-27	
500		0.470	-95	7.373	113	0.078	59	0.568	-40	
1000		0.327	-132	4.148	92	0.114	62	0.436	-43	
1500		0.271	-153	2.921	81	0.151	66	0.413	-44	
2000		0.218	-177	2.295	72	0.188	69	0.394	-41	
3000		0.237	138	1.661	58	0.265	70	0.372	-43	

Table 3. MRF947 Series Common Emitter S-Parameters

VCE (Volts)	I _C (mA)	f (MHz)	S ₁₁		S ₂₁		S ₁₂		S ₂₂	
			Mag	∠φ	Mag	∠φ	Mag	∠φ	Mag	∠φ
2.0	10	100	0.608	-43	21.812	149	0.022	72	0.859	-23
		200	0.488	-73	16.618	129	0.038	65	0.689	-35
		500	0.330	-119	8.427	103	0.065	66	0.438	-41
		1000	0.262	-152	4.484	87	0.109	71	0.354	-40
		1500	0.227	-169	3.114	77	0.155	73	0.358	-42
		2000	0.197	166	2.423	69	0.198	73	0.355	-38
		3000	0.233	128	1.755	57	0.281	71	0.338	-40
	30	100	0.353	-100	25.543	131	0.018	70	0.653	-29
		200	0.353	-135	15.823	112	0.026	68	0.484	-34
		500	0.346	-163	6.979	93	0.054	76	0.367	-29
		1000	0.337	177	3.637	80	0.103	79	0.351	-30
		1500	0.324	166	2.518	71	0.150	79	0.372	-36
		2000	0.319	148	1.975	63	0.197	78	0.378	-35
		3000	0.374	122	1.441	51	0.290	75	0.363	-42
6.0	0.5	100	0.978	-9	1.791	173	0.024	86	0.995	-4
		200	0.964	-17	1.889	166	0.049	80	0.994	-7
		500	0.932	-40	1.643	146	0.110	67	0.953	-16
		1000	0.765	-73	1.473	121	0.165	50	0.869	-28
		1500	0.688	-100	1.206	98	0.184	39	0.812	-35
		2000	0.554	-123	1.099	84	0.162	38	0.735	-38
		3000	0.463	-174	0.823	64	0.136	63	0.671	-46
	2.0	100	0.918	-15	6.614	168	0.023	84	0.983	-7
		200	0.862	-29	6.456	157	0.045	75	0.956	-14
		500	0.729	-62	5.010	131	0.089	60	0.809	-27
		1000	0.504	-99	3.344	106	0.121	53	0.654	-35
		1500	0.397	-123	2.485	90	0.137	55	0.599	-38
		2000	0.295	-146	2.013	78	0.152	62	0.553	-37
		3000	0.257	162	1.452	62	0.202	73	0.523	-40
	5.0	100	0.806	-24	14.025	161	0.022	78	0.947	-13
		200	0.704	-45	12.425	144	0.040	70	0.861	-23
		500	0.487	-85	7.751	116	0.068	62	0.627	-33
		1000	0.316	-120	4.399	95	0.101	65	0.505	-35
		1500	0.245	-141	3.112	83	0.134	69	0.488	-36
		2000	0.177	-166	2.447	74	0.167	72	0.473	-33
		3000	0.185	140	1.743	61	0.237	74	0.457	-36
	10	100	0.657	-37	22.098	151	0.019	75	0.888	-18
		200	0.526	-64	17.304	132	0.033	68	0.741	-29
		500	0.328	-105	9.028	106	0.056	67	0.509	-33
		1000	0.228	-138	4.844	89	0.096	73	0.438	-31
		1500	0.184	-156	3.359	80	0.138	75	0.440	-34
		2000	0.140	175	2.591	72	0.175	76	0.441	-31
		3000	0.172	126	1.852	60	0.249	75	0.430	-33
	20	100	0.492	-53	28.934	142	0.017	72	0.808	-23
		200	0.372	-85	19.971	121	0.028	70	0.630	-31
		500	0.249	-127	9.335	100	0.053	74	0.454	-28
		1000	0.201	-156	4.878	86	0.094	78	0.418	-27
		1500	0.174	-171	3.358	77	0.138	79	0.432	-30
		2000	0.149	161	2.580	70	0.177	78	0.444	-28
		3000	0.193	121	1.852	58	0.253	76	0.435	-32

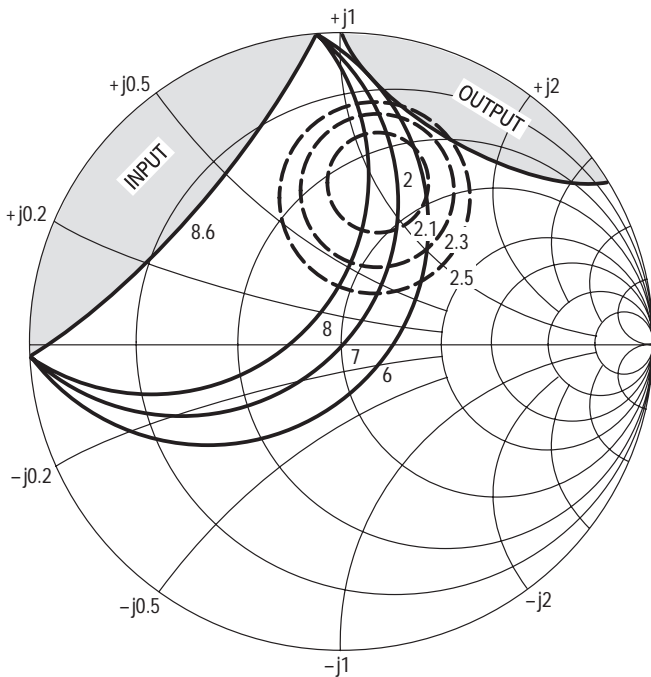
Table 3. MRF947 Series Common Emitter S-Parameters (continued)



$V_{CE} = 1.0\text{ V}$
 $I_C = 0.5\text{ mA}$
 □ — AREA OF INSTABILITY

f (GHz)	NF OPT (dB)	Γ_{MS} NF OPT	R_N	K
0.5	1.54	$0.71 \angle 39^\circ$	38	0.28

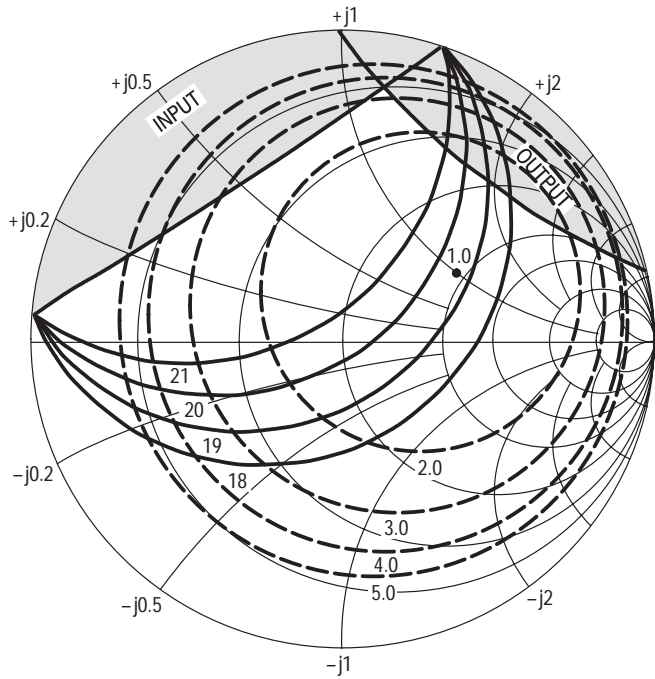
Figure 14. MMBR941LT1, T3 Constant Gain and Noise Figure Contours (f = 1.0 GHz)



$V_{CE} = 1.0\text{ V}$
 $I_C = 0.5\text{ mA}$
 □ — AREA OF INSTABILITY

f (GHz)	NF OPT (dB)	Γ_{MS} NF OPT	R_N	K
1.0	1.95	$0.55 \angle 76^\circ$	28	0.51

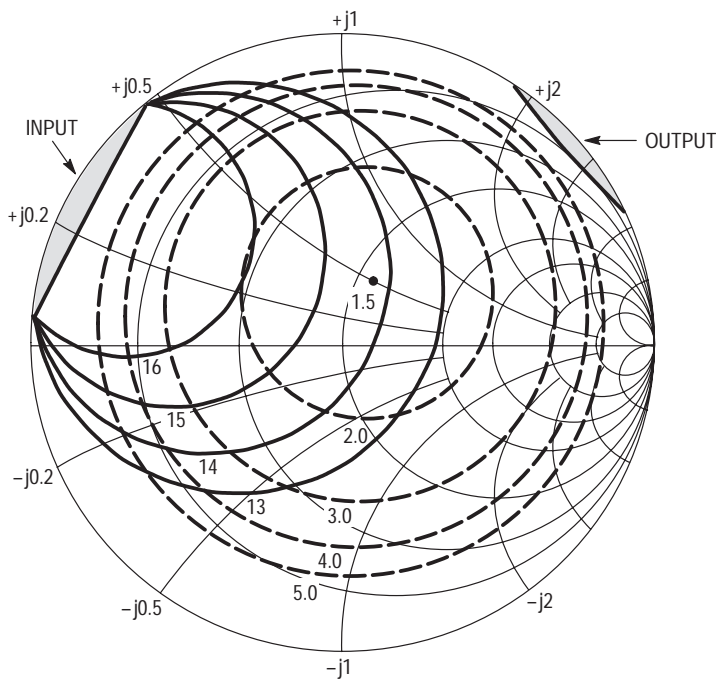
Figure 15. MMBR941LT1, T3 Constant Gain and Noise Figure Contours (f = 0.5 GHz)



$V_{CE} = 6.0 \text{ V}$
 $I_C = 5.0 \text{ mA}$
 [shaded box] — AREA OF INSTABILITY

f (GHz)	NF OPT (dB)	Γ_{MS} NF OPT	R_N	K
0.5	1.0	$0.43 \angle 30^\circ$	18	0.58

Figure 16. MMBR941LT1, T3 Constant Gain and Noise Figure Contours (f = 0.5 GHz)



$V_{CE} = 6.0 \text{ V}$
 $I_C = 5.0 \text{ mA}$
 [shaded box] — AREA OF INSTABILITY

f (GHz)	NF OPT (dB)	Γ_{MS} NF OPT	R_N	K
1.0	1.5	$0.22 \angle 64^\circ$	13	0.93

Figure 17. MMBR941LT1, T3 Constant Gain and Noise Figure Contours (f = 1.0 GHz)

$V_{CE} = 6\text{ V}$
 $I_C = 5\text{ mA}$

f (GHz)	NF OPT	Γ_O	R_N	K
1.0	1.5 dB	$0.33 \angle 77^\circ$	14	0.87

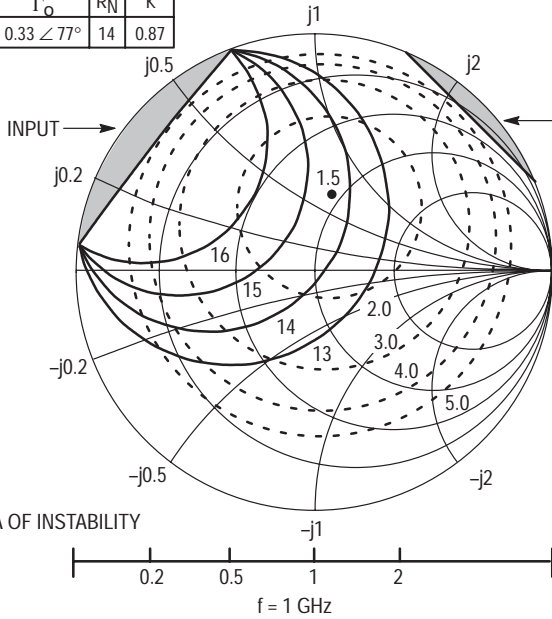


Figure 18. MRF947 Series Constant Gain and Noise Figure Contours

$V_{CE} = 6\text{ V}$
 $I_C = 5\text{ mA}$

f (GHz)	NF OPT	Γ_O	R_N	K
1.5	1.75 dB	$0.26 \angle 141^\circ$	15	0.96

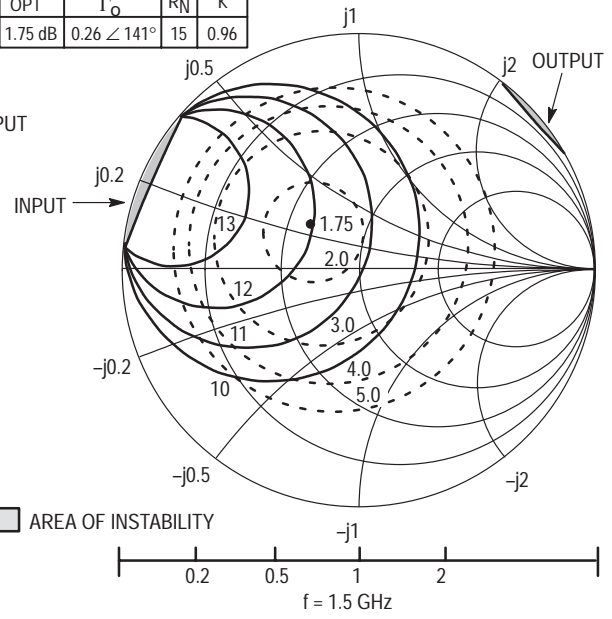


Figure 19. MRF947 Series Constant Gain and Noise Figure Contours

$V_{CE} = 1\text{ V}$
 $I_C = 0.5\text{ mA}$

f (GHz)	NF OPT	Γ_{MS} NF OPT	R_N	K
1.0	1.95 dB	$0.59 \angle 72^\circ$	30	0.50

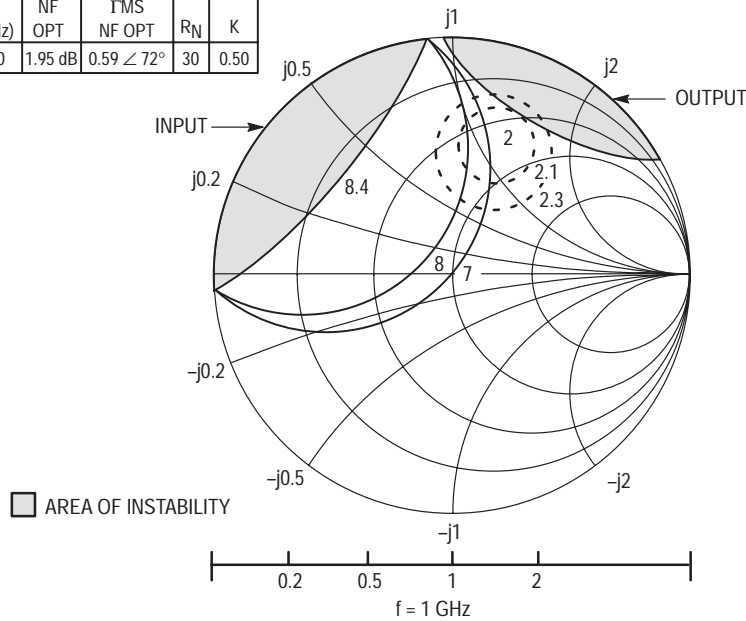
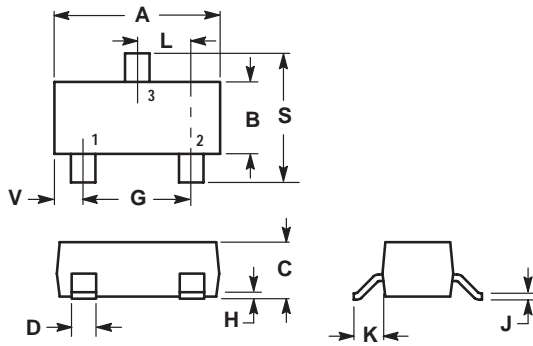


Figure 20. MRF947 Series Constant Gain and Noise Figure Contours

PACKAGE DIMENSIONS



NOTES:

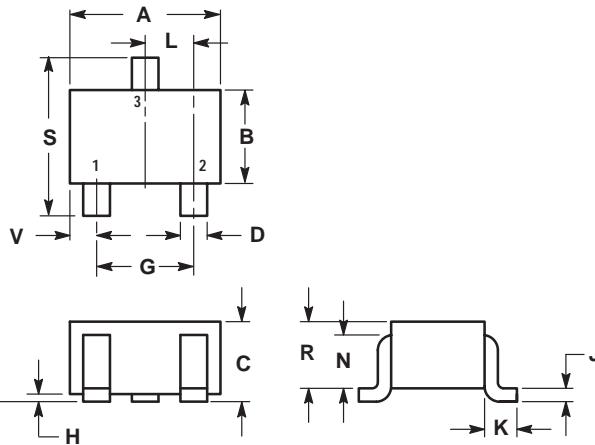
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

STYLE 6:

1. BASE
2. EMITTER
3. COLLECTOR

**CASE 318-08
ISSUE AF
MMBR941LT1, T3, MMBR941BLT1**



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.035	0.049	0.90	1.25
D	0.012	0.016	0.30	0.40
G	0.047	0.055	1.20	1.40
H	0.000	0.004	0.00	0.10
J	0.004	0.010	0.10	0.25
K	0.017 REF		0.425 REF	
L	0.026 BSC		0.650 BSC	
N	0.028 REF		0.700 REF	
R	0.031	0.039	0.80	1.00
S	0.079	0.087	2.00	2.20
V	0.012	0.016	0.30	0.40

STYLE 3:

1. BASE
2. EMITTER
3. COLLECTOR

**CASE 419-02
ISSUE J
MRF947AT1, MRF947BT1,
MRF947T1, T3**

0.05 (0.002)


LIFETIME BUY

LAST SHIP: 26MAR02

LAST ORDER: 25SEP01

LIFETIME BUY

LAST ORDER: 25SEP01 LAST SHIP: 26MAR02

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